

FEATURES

High output accuracy

REF01: 10.0 V, $\pm 0.3\%$ maximum

REF02: 5.0 V, $\pm 0.3\%$ maximum

REF03: 2.5 V, $\pm 0.6\%$ maximum

Adjustable output: $\pm 3\%$ minimum

Excellent temperature stability

REF01: 8.5 ppm/ $^{\circ}\text{C}$ maximum

REF02: 8.5 ppm/ $^{\circ}\text{C}$ maximum

REF03: 50 ppm/ $^{\circ}\text{C}$ maximum

Low noise

REF01: 30 μV p-p typical

REF02: 15 μV p-p typical

REF03: 6 μV p-p typical

High supply voltage range: up to 36 V maximum

Low supply current: 1.4 mA maximum

High load-driving capability: 10 mA maximum

Temperature output function

APPLICATIONS

Precision data systems

High resolution converters

Industrial process control systems

Precision instruments

Military and aerospace applications

GENERAL DESCRIPTION

The REF0x series of precision voltage references provide a stable 10.0 V, 5.0 V, or 2.5 V output with minimal change in response to variations in supply voltage, ambient temperature or load conditions. The parts are available in 8-lead SOIC, PDIP, CERDIP, and TO-99 packages, as well as 20-terminal LCC packages (883 only), furthering the parts' usability in both standard and high stress applications.

With an external buffer and a simple resistor network, the TEMP terminal can be used for temperature sensing and approximation. A TRIM terminal is also provided on the device for fine adjustment of the output voltage.

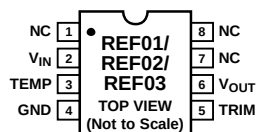
The small footprint, wide supply range, and application versatility make the REF0x series of references ideal for general-purpose and space-constrained applications.

Newer designs should use the ADR0x series of references, which offer higher accuracy and temperature stability over a wider operating temperature range, while maintaining full pin-for-pin compatibility with the REF0x series. This data sheet applies to commercial-grade products only. Contact sales or visit analog.com for military-grade (883) data sheets.

Table 1. Selection Guide

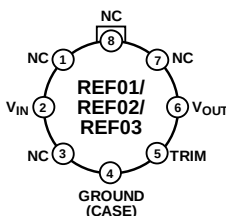
Part Number	Output Voltage	Input Voltage Range
REF01	10.0 V	12 V to 36 V
REF02	5.0 V	7.0 V to 36 V
REF03	2.5 V	4.5 V to 36 V

PIN CONFIGURATIONS



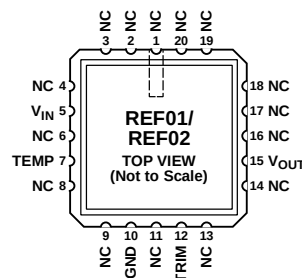
NC = NO CONNECT. DO NOT CONNECT ANYTHING ON THESE PINS. SOME OF THEM ARE RESERVED FOR FACTORY TESTING PURPOSES.

Figure 1. 8-Lead PDIP (P-Suffix),
8-Lead CERDIP (Z-Suffix),
8-Lead SOIC (S-Suffix)



NC = NO CONNECT. DO NOT CONNECT ANYTHING ON THESE PINS. SOME OF THEM ARE RESERVED FOR FACTORY TESTING PURPOSES.

Figure 2. 8-Lead TO-99 (J-Suffix)



NC = NO CONNECT. DO NOT CONNECT ANYTHING ON THESE PINS. SOME OF THEM ARE RESERVED FOR FACTORY TESTING PURPOSES.

Figure 3. 20-Terminal LCC (RC-Suffix;
883 Parts Only)

Rev. K

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REVISION HISTORY

10/10—Rev. J to Rev. K

Deleted Negative References Section and Figure 39; Renumbered Sequentially	16
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10/09—Rev. J: Initial Version

Updated Format	Universal
Combined REF01, REF02, and REF03 Data Sheets	Universal
Changes to Absolute Maximum Input Voltage	6

SPECIFICATIONS

REF01 SPECIFICATIONS

$V_{IN} = 15\text{ V}$, $T_A = 25^\circ\text{C}$, $I_{LOAD} = 0\text{ mA}$, all grades, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
OUTPUT VOLTAGE	V_O	A and E grades	9.97	10.00	10.03	V
		H grade	9.95	10.00	10.05	V
		C grade	9.90	10.00	10.10	V
OUTPUT ADJUSTMENT RANGE ¹	ΔV_{TRIM}	A, E and H grades, POT = 10 k Ω	± 3.0	± 3.3		%
		C grade, POT = 10 k Ω	± 2.7	± 3.0		%
INITIAL ACCURACY	V_{OERR}	A and E grades			± 30	mV
					± 0.3	%
		H grade			± 50	mV
					± 0.5	%
		C grade			± 100	mV
					± 1.0	%
TEMPERATURE COEFFICIENT	TCV_O	A and E grades, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		3.0	8.5	ppm/ $^\circ\text{C}$
		H grade, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$		10	25	ppm/ $^\circ\text{C}$
		C grade, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)		20	65	ppm/ $^\circ\text{C}$
		C grade, $-40 \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)		20	65	ppm/ $^\circ\text{C}$
LINE REGULATION ²	$\Delta V_O/\Delta V_{IN}$	A, E and H grades, $V_{IN} = 13\text{ V to }33\text{ V}$	60	100		ppm/V
		A, E and H grades, $V_{IN} = 13\text{ V to }33\text{ V}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$	70	120		ppm/V
		A, E and H grades, $V_{IN} = 13\text{ V to }33\text{ V}$, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	90	150		ppm/V
		C grade, $V_{IN} = 13\text{ V to }33\text{ V}$	90	150		ppm/V
		C grade, $V_{IN} = 13\text{ V to }30\text{ V}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)	110	180		ppm/V
		C grade, $V_{IN} = 13\text{ V to }30\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)	110	180		ppm/V
LOAD REGULATION ²	$\Delta V_O/\Delta I_{LOAD}$	A and E grades, $I_{LOAD} = 0\text{ mA to }10\text{ mA}$	50	80		ppm/mA
		A and E grades, $I_{LOAD} = 0\text{ mA to }8\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$	60	100		ppm/mA
		A and E grades, $I_{LOAD} = 0\text{ mA to }8\text{ mA}$, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	90	150		ppm/mA
		H grade, $I_{LOAD} = 0\text{ mA to }10\text{ mA}$	60	100		ppm/mA
		H grade, $I_{LOAD} = 0\text{ mA to }8\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$	70	120		ppm/mA
		H grade, $I_{LOAD} = 0\text{ mA to }8\text{ mA}$, $-50^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	90	150		ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to }8\text{ mA}$	60	150		ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to }5\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)	80	180		ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to }5\text{ mA}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)	80	180		ppm/mA
DROPOUT VOLTAGE	V_{DO}				2	V
QUIESCENT CURRENT	I_{IN}	A, E, and H grades	1.0	1.4		mA
		C grade	1.0	1.6		mA
LOAD CURRENT	I_{LOAD}	A, E, and H grades C grade		10		mA
				8		mA
				-0.3		mA
SHORT CIRCUIT TO GND	I_{SC}	$V_O = 0\text{ V}$	30			mA
VOLTAGE NOISE	$e_{N\text{ p-p}}$	0.1 Hz to 10.0 Hz (-S, -Z and -P packages)	30			$\mu\text{V p-p}$
		0.1 Hz to 10.0 Hz (-J package)	35			$\mu\text{V p-p}$
LONG-TERM STABILITY ³	ΔV_O	After 1000 hours of operation	50			ppm
TURN-ON SETTLING TIME	t_R	Output settling to within $\pm 0.1\%$ of final value	5			μs
TEMPERATURE SENSOR ⁴	V_{TEMP} TCV_{TEMP}		580			mV
			1.96			mV/ $^\circ\text{C}$

¹ Refer to the Output Adjustment section.

² Specification includes the effects of self-heating.

³ Long-term stability is noncumulative; the drift in subsequent 1000-hour periods is significantly lower than in the first 1000-hour periods. Refer to Application Note [AN-713](#).

⁴ Refer to the Temperature Monitoring section.

REF01/REF02/REF03

REF02 SPECIFICATIONS

$V_{IN} = 15\text{ V}$, $T_A = 25^\circ\text{C}$, $I_{LOAD} = 0\text{ mA}$, all grades, unless otherwise noted. Nongraded refers to REF02Z.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
OUTPUT VOLTAGE	V_O	A and E grades	4.985	5.000	5.015	V
		H grade and nongraded	4.975	5.000	5.025	V
		C grade	4.950	5.000	5.050	V
OUTPUT ADJUSTMENT RANGE ¹	ΔV_{TRIM}	A, E, H grades and nongraded, POT = 10 k Ω	± 3.0	± 6.0		%
		C grade, POT = 10 k Ω	± 2.7	± 6.0		%
INITIAL ACCURACY	V_{OERR}	A and E grades			± 15	mV
					± 0.3	%
		H grade and nongraded			± 25	mV
					± 0.5	%
		C grade			± 50	mV
TEMPERATURE COEFFICIENT	TCV_O	A grade and non-graded, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		3	8.5	ppm/ $^\circ\text{C}$
		E and H grades, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$		10	25	ppm/ $^\circ\text{C}$
		C grade, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)		20	65	ppm/ $^\circ\text{C}$
		C grade, $-40 \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)		20	65	ppm/ $^\circ\text{C}$
LINE REGULATION ²	$\Delta V_O / \Delta V_{IN}$	A, E, H grades and nongraded, $V_{IN} = 8\text{ V to } 36\text{ V}$		60	100	ppm/V
		A, E, H grades and nongraded, $V_{IN} = 8\text{ V to } 36\text{ V}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$		70	120	ppm/V
		A, E, H grades and nongraded, $V_{IN} = 8\text{ V to } 36\text{ V}$, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		90	150	ppm/V
		C grade, $V_{IN} = 8\text{ V to } 36\text{ V}$		90	150	ppm/V
		C grade, $V_{IN} = 8\text{ V to } 36\text{ V}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)		110	180	ppm/V
		C grade, $V_{IN} = 8\text{ V to } 36\text{ V}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)		110	180	ppm/V
LOAD REGULATION ²	$\Delta V_O / \Delta I_{LOAD}$	A and E grades, $I_{LOAD} = 0\text{ mA to } 10\text{ mA}$		60	100	ppm/mA
		A and E grades, $I_{LOAD} = 0\text{ mA to } 8\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$		60	100	ppm/mA
		A and E grades, $I_{LOAD} = 0\text{ mA to } 8\text{ mA}$, $-55^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		70	120	ppm/mA
		H grade and nongraded, $I_{LOAD} = 0\text{ mA to } 10\text{ mA}$		60	100	ppm/mA
		H grade and nongraded, $I_{LOAD} = 0\text{ mA to } 8\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$		70	120	ppm/mA
		H grade and nongraded, $I_{LOAD} = 0\text{ mA to } 8\text{ mA}$, $-50^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		90	150	ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to } 8\text{ mA}$		60	150	ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to } 5\text{ mA}$, $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ (-J and -Z packages)		80	180	ppm/mA
		C grade, $I_{LOAD} = 0\text{ mA to } 5\text{ mA}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ (-P and -S packages)		80	180	ppm/mA
DROPOUT VOLTAGE	V_{DO}				2	V
QUIESCENT CURRENT	I_{IN}	A, E, H grades and nongraded		1.0	1.4	mA
		C grade		1.0	1.6	mA
LOAD CURRENT	I_{LOAD}	A, E, H grades and nongraded			10	mA
		C grade			8	mA
					-0.3	mA
SHORT CIRCUIT TO GND	I_{SC}	$V_O = 0\text{ V}$		30		mA
VOLTAGE NOISE	$e_{N\text{ p-p}}$	0.1 Hz to 10.0 Hz (-S, -Z and -P packages)		15		$\mu\text{V p-p}$
		0.1 Hz to 10.0 Hz (-J package)		20		$\mu\text{V p-p}$
LONG-TERM STABILITY ³	ΔV_O	After 1000 hours of operation		50		ppm
TURN-ON SETTLING TIME	t_R	Output settling to within $\pm 0.1\%$ of final value		5		μs
TEMPERATURE SENSOR ⁴	V_{TEMP}			580		mV
	TCV_{TEMP}			1.96		mV/ $^\circ\text{C}$

¹ Refer to the Output Adjustment section.

² Specification includes the effects of self-heating.

³ Long-term stability is noncumulative; the drift in subsequent 1000-hour periods is significantly lower than in the first 1000-hour periods. Refer to Application Note [AN-713](#).

⁴ Refer to the Temperature Monitoring section.

REF03 SPECIFICATIONS

$V_{IN} = 15\text{ V}$, $-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$, $I_{LOAD} = 0\text{ mA}$, unless otherwise noted.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
OUTPUT VOLTAGE	V_O		2.495	2.500	2.515	V
OUTPUT ADJUSTMENT RANGE ¹	ΔV_{TRIM}	POT = 10 k Ω	± 6	± 11		%
INITIAL ACCURACY	V_{OERR}				± 15 ± 0.6	mV %
TEMPERATURE COEFFICIENT	TCV_O			10	50	ppm/ $^{\circ}\text{C}$
LINE REGULATION ²	$\Delta V_O / \Delta V_{IN}$	$V_{IN} = 4.5\text{ V to }33\text{ V}$		20	50	ppm/V
LOAD REGULATION ²	$\Delta V_O / \Delta I_{LOAD}$	$I_{LOAD} = 0\text{ mA to }10\text{ mA}$		60	100	ppm/mA
DROPOUT VOLTAGE	V_{DO}				2	V
QUIESCENT CURRENT	I_{IN}			1.0	1.4	mA
LOAD CURRENT	I_{LOAD}					
Sourcing					10	mA
Sinking					-0.3	mA
SHORT CIRCUIT TO GND	I_{SC}	$V_O = 0\text{ V}$		24		mA
VOLTAGE NOISE	$e_{N\text{ p-p}}$	0.1 Hz to 10.0 Hz		6		$\mu\text{V p-p}$
LONG-TERM STABILITY ³	ΔV_O	After 1000 hours of operation		50		ppm
TURN-ON SETTLING TIME	t_R	Output settling to within $\pm 0.1\%$ of final value		5		μs
TEMPERATURE SENSOR ⁴						
Voltage Output at TEMP Pin	V_{TEMP}			580		mV
Temperature Sensitivity	TCV_{TEMP}			1.96		mV/ $^{\circ}\text{C}$

¹ Refer to the Output Adjustment section.

² Specification includes the effects of self-heating.

³ Long-term stability is noncumulative; the drift in subsequent 1000-hour periods is significantly lower than in the first 1000-hour periods. Refer to Application Note [AN-713](#).

⁴ Refer to the Temperature Monitoring section.

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Input Voltage	36.0 V
Output Short Circuit Duration	Indefinite
Operating Temperature Range	
REF01A, REF02A	–55°C to +125°C
REF01CP, REF01CS, REF01E, REF01H, REF02CP, REF02CS, REF02E, REF02H, REF03G	–40°C to +85°C
REF01CJ	0°C to +70°C
Storage Temperature Range	
-J, -S, -Z and -RC Packages	–65°C to +150°C
-P Package	–65°C to +125°C
Junction Temperature Range (T _J)	–65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-lead SOIC (S)	130	43	°C/W
8-lead PDIP (P)	110	50	°C/W
8-lead Cerdip (Z)	162	26	°C/W
TO-99 (J)	170	24	°C/W

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

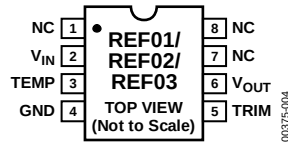


Figure 4. 8-Lead PDIP (P-Suffix), 8-Lead CERDIP (Z-Suffix), 8-Lead SOIC (S-Suffix) Pin Configuration

Table 4. Pin Function Descriptions—PDIP, CERDIP, and SOIC Packages

Pin No.	Mnemonic	Description
1, 7, 8	NC	No Internal Connection. Leave floating or tied to ground in actual application.
2	V _{IN}	Supply Voltage Input.
3	TEMP	Temperature (Band Gap) Output. Refer to the Temperature Monitoring section.
4	GND	Ground Connection.
5	TRIM	Output Voltage Trim. Refer to the Output Adjustment section.
6	V _{OUT}	Reference Voltage Output.

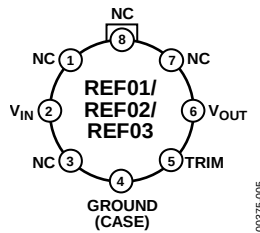


Figure 5. 8-Lead TO-99 (J-Suffix) Pin Configuration

Table 5. Pin Function Descriptions—8-Lead TO-99 Package

Pin No.	Mnemonic	Description
1, 3, 7, 8	NC	No Internal Connection. Leave floating or tied to ground in actual application.
2	V _{IN}	Supply Voltage Input.
4	GND	Ground Connection.
5	TRIM	Output Voltage Trim. Refer to the Output Adjustment section.
6	V _{OUT}	Reference Voltage Output.

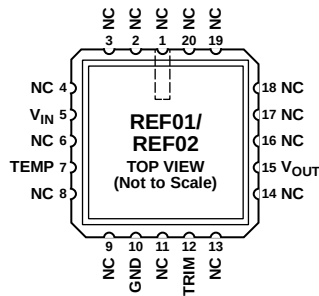


Figure 6. 20-Terminal LCC (RC-Suffix) Pin Configuration

Table 6. Pin Function Descriptions—20-Terminal LCC Package

Terminal No.	Mnemonic	Description
1 to 4, 6, 8, 9, 11, 13, 14, 16 to 20	NC	No Internal Connection. Leave floating or tied to ground in actual application.
5	V _{IN}	Supply Voltage Input.
7	TEMP	Temperature (Band Gap) Output. Refer to the Temperature Monitoring section.
10	GND	Ground Connection.
12	TRIM	Output Voltage Trim. Refer to the Output Adjustment section.
15	V _{OUT}	Reference Voltage Output.

TYPICAL PERFORMANCE CHARACTERISTICS

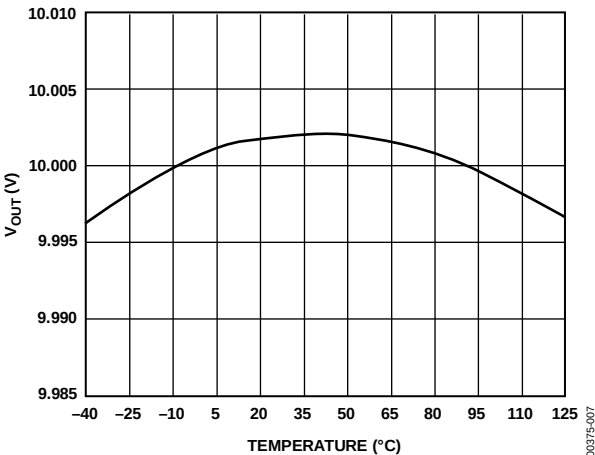


Figure 7. REF01 Typical Output Voltage vs. Temperature

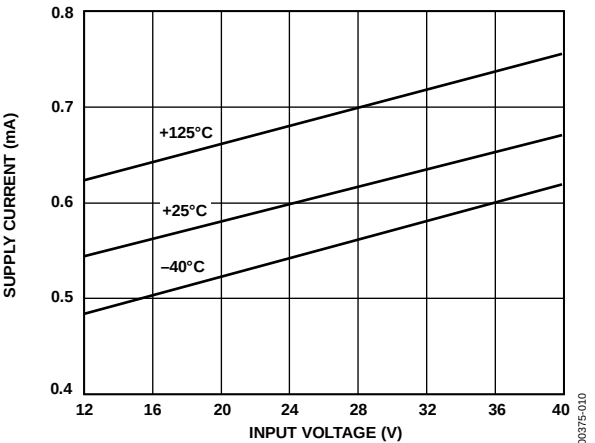


Figure 10. REF01 Supply Current vs. Input Voltage

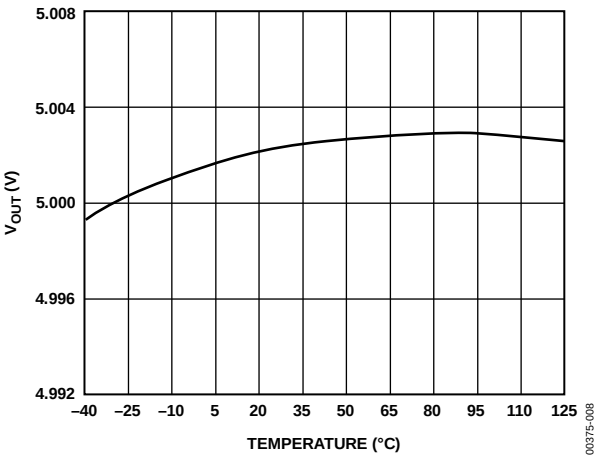


Figure 8. REF02 Typical Output Voltage vs. Temperature

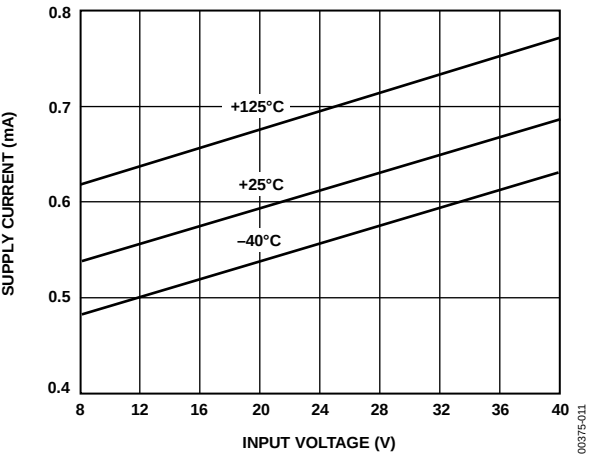


Figure 11. REF02 Supply Current vs. Input Voltage

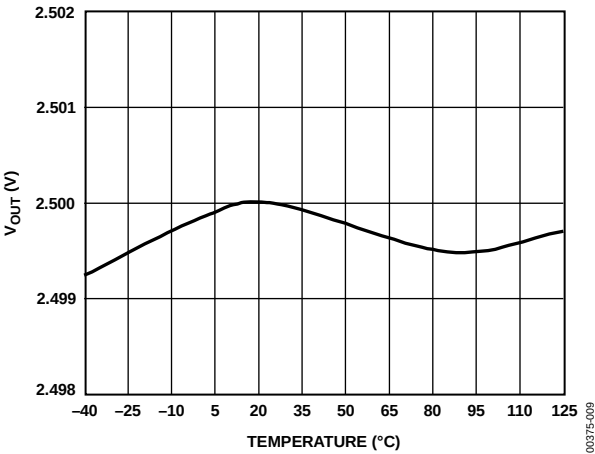


Figure 9. REF03 Typical Output Voltage vs. Temperature

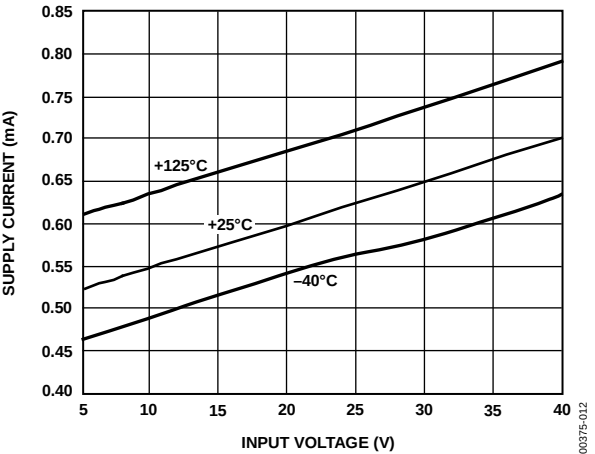


Figure 12. REF03 Supply Current vs. Input Voltage

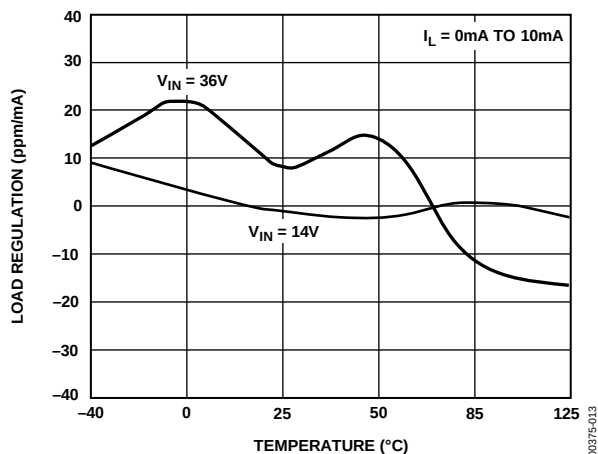


Figure 13. REF01 Load Regulation vs. Temperature

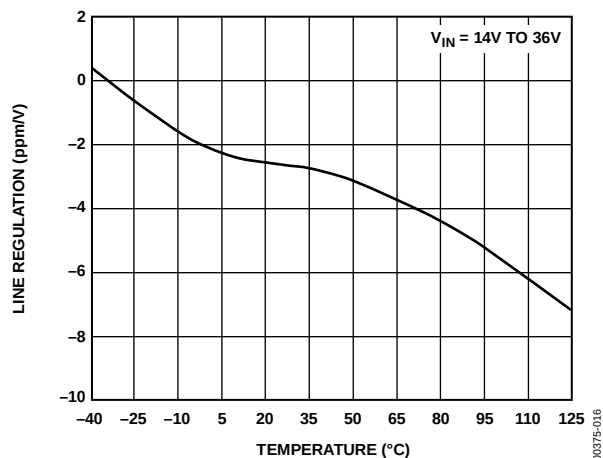


Figure 16. REF01 Line Regulation vs. Temperature

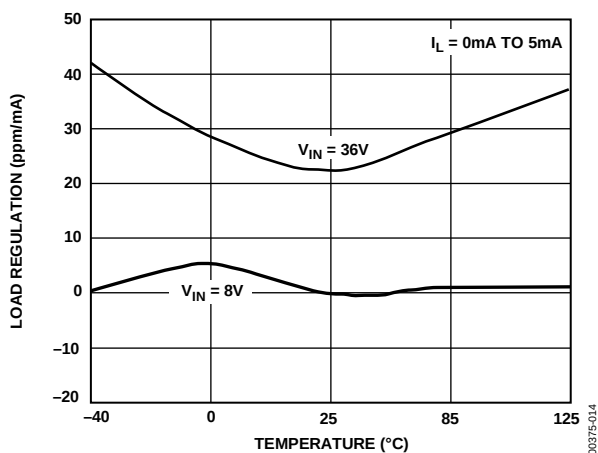


Figure 14. REF02 Load Regulation vs. Temperature

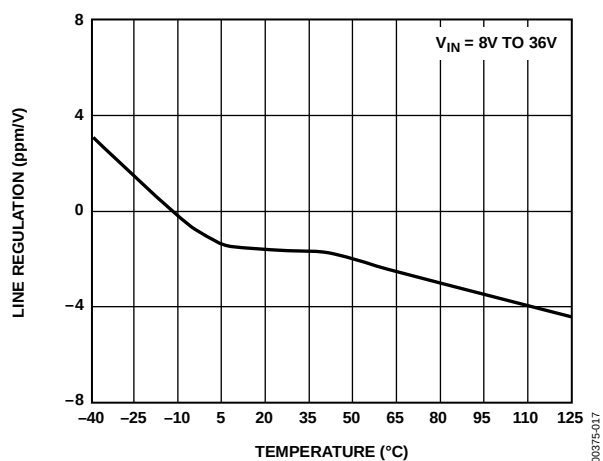


Figure 17. REF02 Line Regulation vs. Temperature

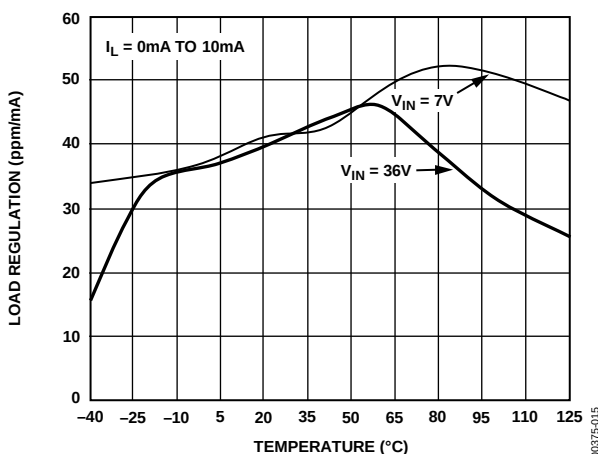


Figure 15. REF03 Load Regulation vs. Temperature

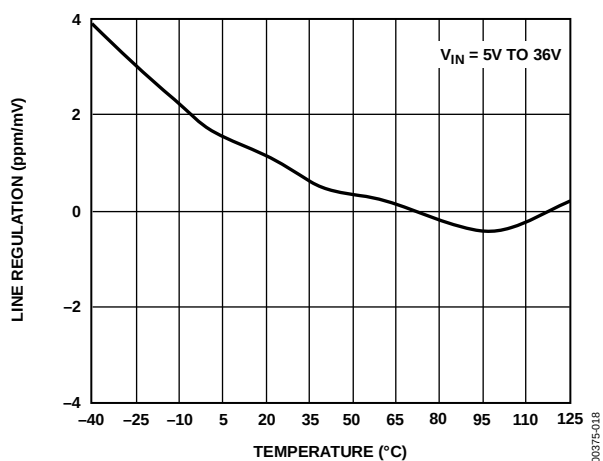


Figure 18. REF03 Line Regulation vs. Temperature

REF01/REF02/REF03

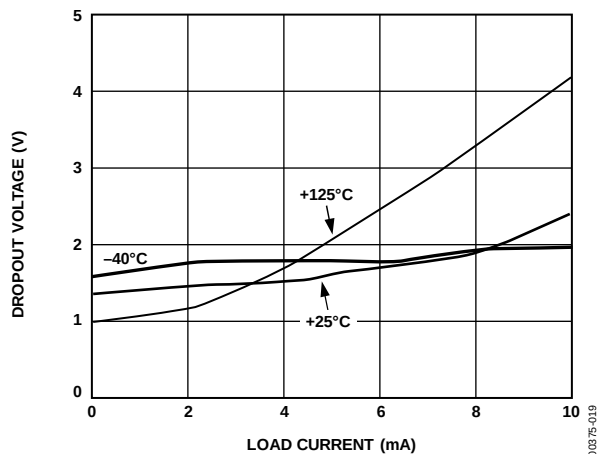


Figure 19. REF01 Dropout Voltage vs. Load Current

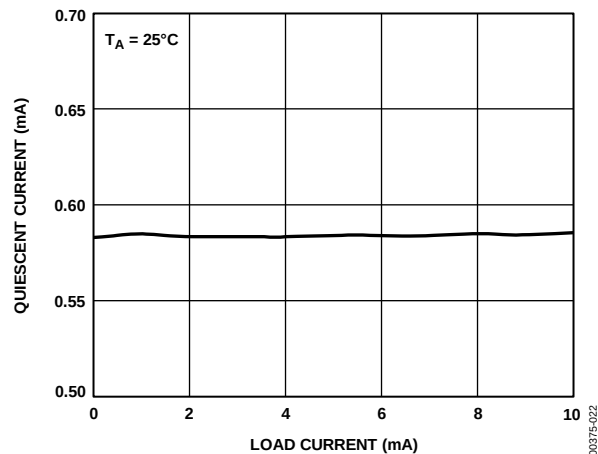


Figure 22. REF01 Quiescent Current vs. Load Current

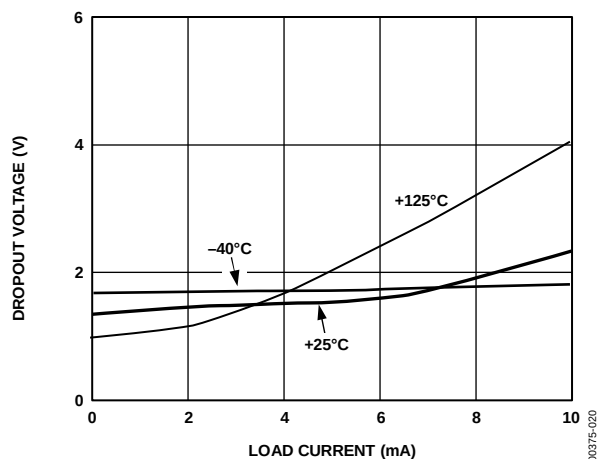


Figure 20. REF02 Dropout Voltage vs. Load Current

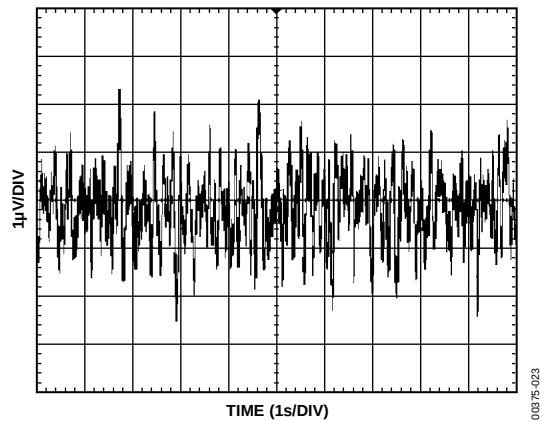


Figure 23. REF02 Typical Low-Frequency Voltage Noise (0.1 Hz to 10.0 Hz)

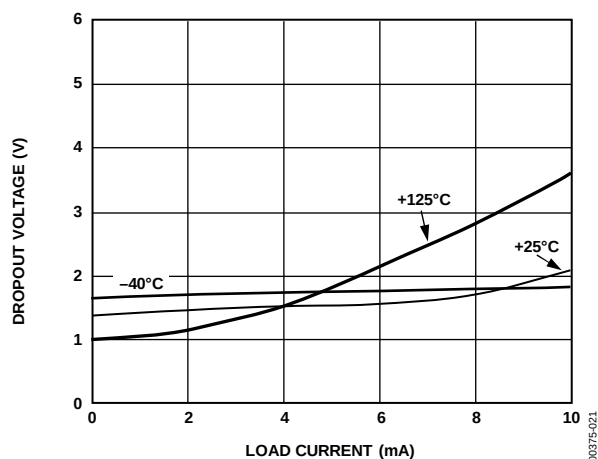


Figure 21. REF03 Dropout Voltage vs. Load Current

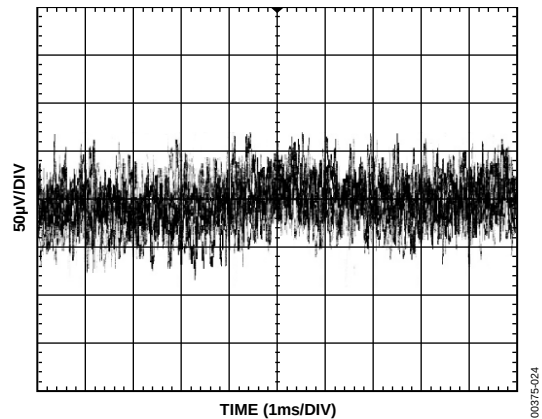


Figure 24. REF02 Typical Wideband Voltage Noise (10 Hz to 10 kHz)

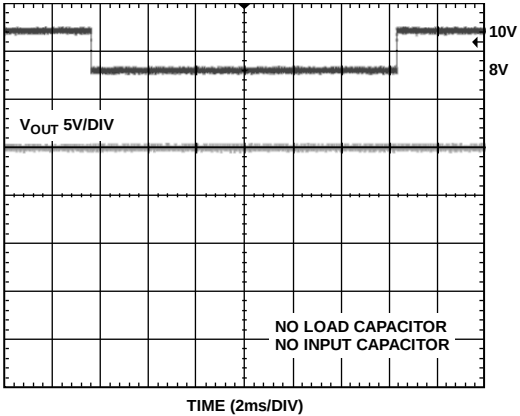


Figure 25. REF02 Line Transient Response

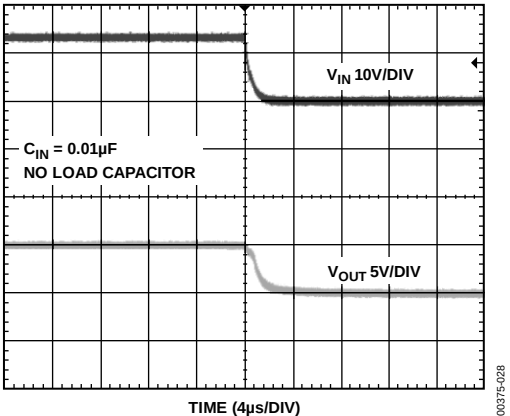


Figure 28. REF02 Turn-Off Response

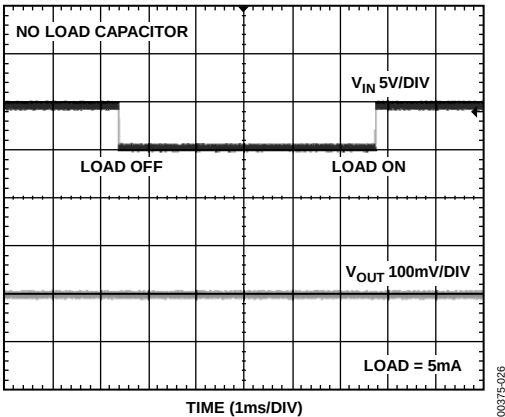


Figure 26. REF02 Load Transient Response

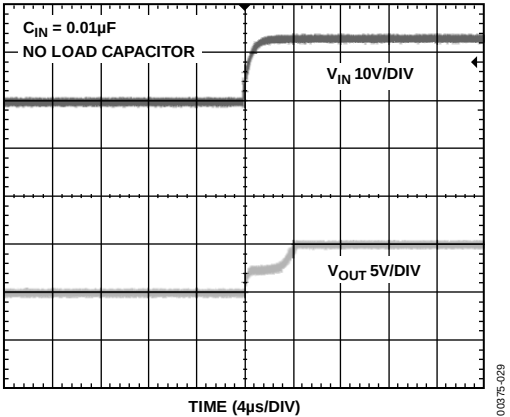


Figure 29. REF02 Turn-On Response

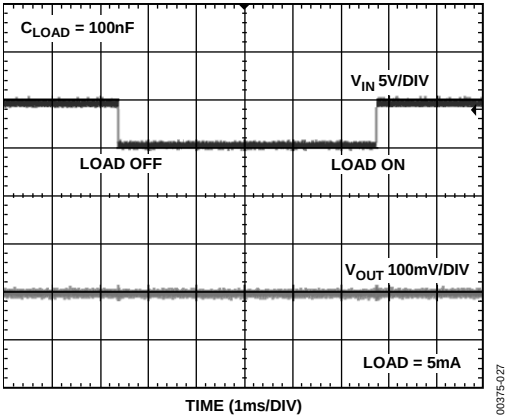


Figure 27. REF02 Load Transient Response

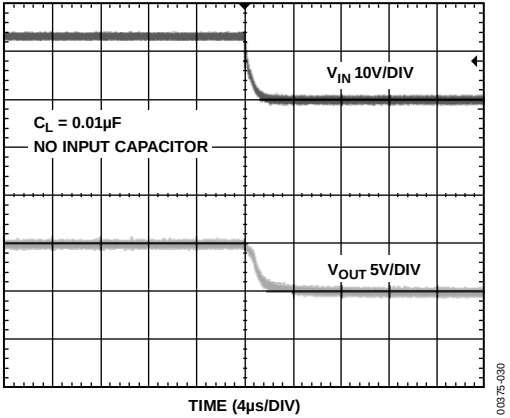


Figure 30. REF02 Turn-Off Response (No Input Capacitor)

REF01/REF02/REF03

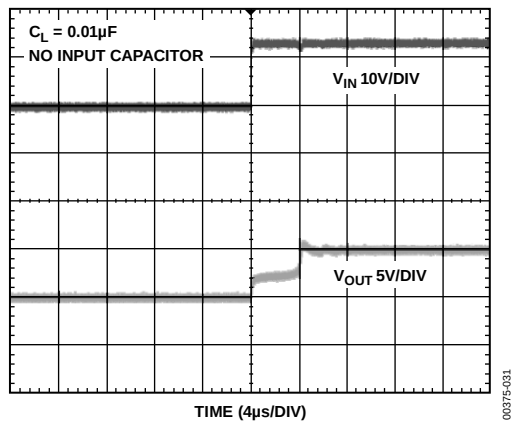


Figure 31. REF02 Turn-Off Response (No Input Capacitor)

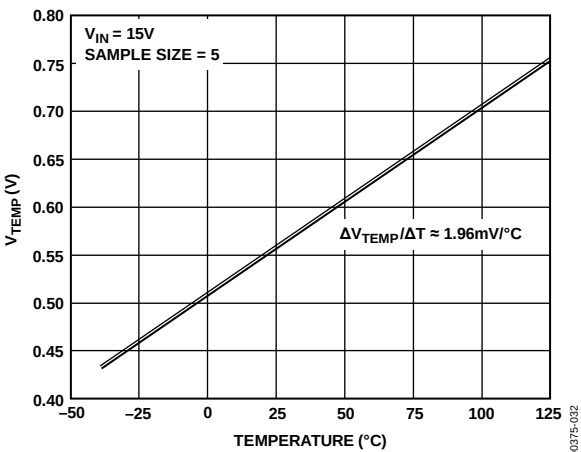


Figure 32. Output Voltage at TEMP Pin vs. Temperature

TERMINOLOGY

Dropout Voltage (V_{DO})

Dropout voltage, sometimes referred to as supply voltage headroom or supply-output voltage differential, is defined as the minimum voltage differential between the input and output necessary for the device to operate.

$$V_{DO} = (V_{IN} - V_{OUT})_{\min} \Big|_{I_L = \text{constant}}$$

Since the dropout voltage depends upon the current passing through the device, it is always specified for a given load current.

Temperature Coefficient (TCV_o)

The temperature coefficient relates the change in output voltage to the change in ambient temperature of the device, as normalized by the output voltage at 25°C. This parameter is expressed in ppm/°C and can be determined by the following equation:

$$TCV_{OUT} = \frac{V_{OUT}(T_2) - V_{OUT}(T_1)}{V_{OUT}(25^\circ\text{C}) \times (T_2 - T_1)} \times 10^6 \text{ [ppm/}^\circ\text{C]}$$

where:

$V_{OUT}(25^\circ\text{C})$ is output voltage at 25°C.

$V_{OUT}(T_1)$ is output voltage at temperature 1.

$V_{OUT}(T_2)$ is output voltage at temperature 2.

Thermally Induced Output Voltage Hysteresis (ΔV_{OUT_HYS})

Thermally induced output voltage hysteresis represents the change in output voltage after the device is exposed to a specified temperature cycle. This may be expressed as either a shift in voltage or a difference in ppm from the nominal output.

$$V_{OUT_HYS} = V_{OUT}(25^\circ\text{C}) - V_{OUT_TC} \text{ [V]}$$

$$V_{OUT_HYS} = \frac{V_{OUT}(25^\circ\text{C}) - V_{OUT_TC}}{V_{OUT}(25^\circ\text{C})} \times 10^6 \text{ [ppm]}$$

where:

$V_{OUT}(25^\circ\text{C})$ is output voltage at 25°C.

V_{OUT_TC} is output voltage after temperature cycling.

Thermal hysteresis occurs mainly as a result of forces exhibited upon the internal die by its packaging. The effect is more pronounced in parts with smaller packages.

Long-Term Stability (ΔV_{OUT_LTD})

Long-term stability refers to the shift in output voltage at 25°C after 1000 hours of operation in a 25°C environment. This may also be expressed as either a shift in voltage or a difference in ppm from the nominal output.

$$\Delta V_{OUT_LTD} = |V_{OUT}(t_1) - V_{OUT}(t_0)| \text{ [V]}$$

$$\Delta V_{OUT_LTD} = \left| \frac{V_{OUT}(t_1) - V_{OUT}(t_0)}{V_{OUT}(t_0)} \right| \times 10^6 \text{ [ppm]}$$

where:

$V_{OUT}(t_0)$ is V_{OUT} at 25°C at time 0.

$V_{OUT}(t_1)$ is V_{OUT} at 25°C after 1000 hours of operation at 25°C.

Line Regulation

Line regulation refers to the change in output voltage in response to a given change in input voltage. It is expressed in either percent per volt, ppm per volt, or microvolt per volt change in input voltage. This parameter accounts for the effects of self-heating.

Load Regulation

Load regulation refers to the change in output voltage in response to a given change in load current, and is expressed in either microvolts per milliamp, ppm per milliamp, or ohms of DC output resistance. This parameter accounts for the effects of self-heating.

REF01/REF02/REF03

THEORY OF OPERATION

REF01, REF02, and REF03 are high precision, low drift 10.0 V, 5.0 V, and 2.5 V voltage references available in a variety of packages. These devices are standard band gap references (see Figure 33). The band gap cell contains two NPN transistors (Q18 and Q19) that differ in emitter area by a factor of 2. The difference in the V_{BE} values of these transistors produces a proportional-to-absolute temperature current (PTAT) through R14, and, when combined with the V_{BE} of Q19, produces a band gap voltage, V_{BG} , that is almost constant over temperature.

With an internal op amp and the feedback network created by R5 and R6, V_O is set precisely at 10.0 V, 5.0 V, or 2.5 V. Precision laser trimming of various resistors and other proprietary circuit techniques are used to further enhance the initial accuracy, temperature curvature, and drift performance of the device.

The PTAT voltage is brought out directly from the band gap, unbuffered, at the TEMP pin. Since this voltage output has a stable 1.96 mV/°C temperature coefficient, users can estimate the temperature change of the device by simply monitoring the change in voltage at this pin.

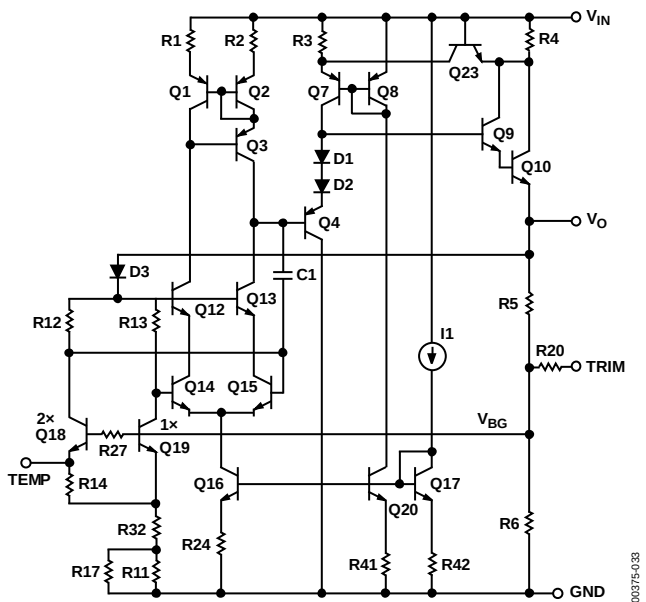


Figure 33. REF0x Simplified Schematic

INPUT AND OUTPUT CAPACITORS

Figure 34 shows the basic input/output capacitor configuration for the REF0x series of references.

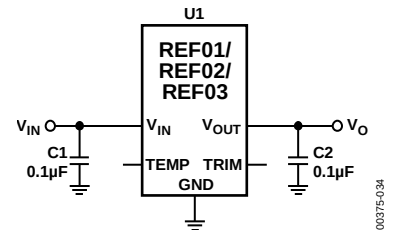


Figure 34. Basic REF0x Capacitor Configuration

While the REF0x series of references are designed to function stably without any external components, connecting a 0.1 µF ceramic capacitor to the output is highly recommended to improve stability and filter out low level voltage noise. An additional 1 µF to 10 µF electrolytic, tantalum, or ceramic capacitor can be added in parallel to improve transient performance in response to sudden changes in load current; however, the designer should keep in mind that doing so increases the turn-on time of the device.

A 1 µF to 10 µF electrolytic, tantalum, or ceramic capacitor can also be connected to the input to improve transient response in applications where the supply voltage may fluctuate. An additional 0.1 µF ceramic capacitor should be connected in parallel to reduce supply noise.

Both input and output capacitors should be mounted as close to the device pins as possible.

OUTPUT ADJUSTMENT

The REF0x trim terminal can be used to adjust the output up or down from the internally trimmed, nominal output voltage. This feature allows the system designer to trim out system errors due to changes in line and load conditions, thermal hysteresis, output offset due to solder reflow, or other error sources. The basic trim circuit configuration is shown in Figure 35.

Table 7 also lists the range of output voltages obtainable from each model in this configuration.

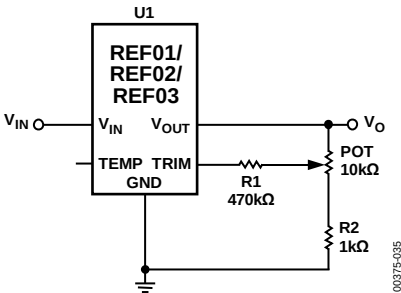


Figure 35. Optional Trim Adjustment Circuit

Table 7. Adjustment Range Using Trim Circuit

Model	V_{OUT} , Low Limit	V_{OUT} , High Limit
REF01	9.70 V	10.05 V
REF02	4.95 V	5.02 V
REF03	2.3 V	2.8 V

Adjustment of the output does not significantly affect the temperature performance of the reference itself, provided the temperature coefficients of the resistors used are low.

BIPOLAR VOLTAGE REFERENCE

Many applications require both a positive and reference voltage of the same magnitude. A simple method of generating such a bipolar reference is shown in Figure 42.

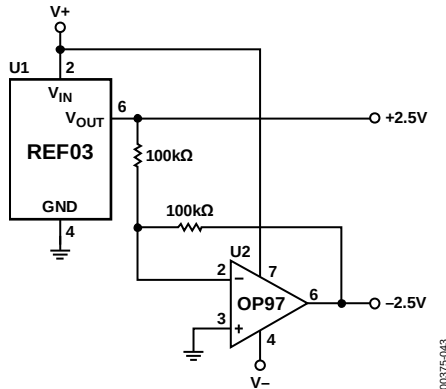


Figure 42. Bipolar Voltage Reference

In this configuration, the negative rail is generated simply with an inverting amplifier with a gain of -1 . A low offset op amp should be used to minimize the voltage error at the negative output.

ADJUSTABLE REFERENCE WITH POSITIVE AND NEGATIVE SWING

The output voltage of the REF0x references can be readily adjusted via a simple trim circuit (explained in the Output Adjustment section). The circuit shown in Figure 43 extends the negative range of adjustment beyond that obtainable with the simple trim circuit by employing a precision op amp with a potentiometer feeding the op amp's noninverting input.

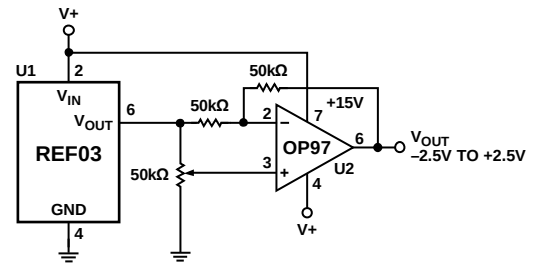
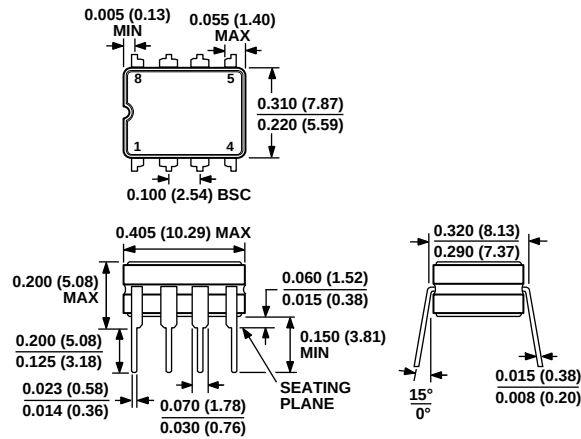


Figure 43. Negatively Adjustable Reference

The voltage output from the op amp can be adjusted by changing the value of the potentiometer: as shown, the op amp outputs +2.5 V when the pot is pulled completely high, and -2.5V when pulled completely low. In this configuration, the load current is sourced by the op amp; therefore, a low offset op amp with a current rating that meets or exceeds the current requirements of the load should be used.

OUTLINE DIMENSIONS

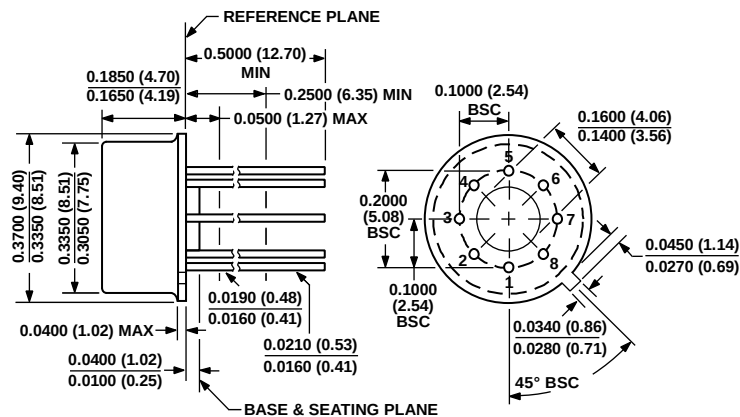


CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 44. 8-Lead Ceramic Dual In-Line Package [CERDIP]

Z-Suffix (Q-8)

Dimensions shown in inches and (millimeters)



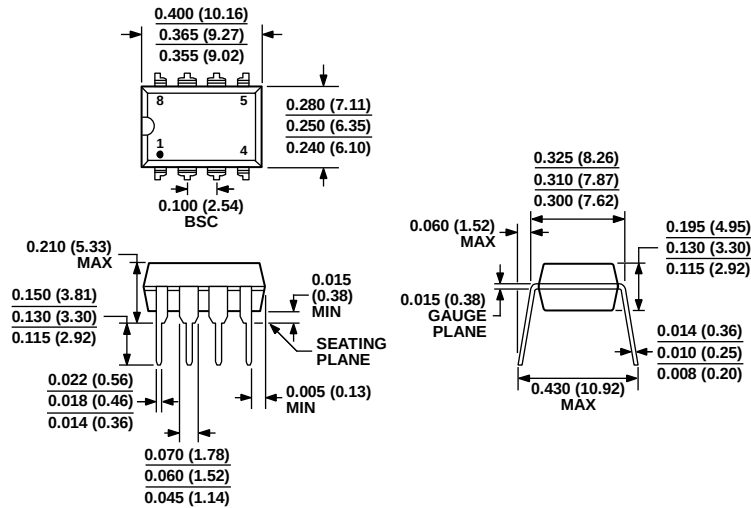
COMPLIANT TO JEDEC STANDARDS MO-002-AK
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 45. 8-Pin Metal Header Package [TO-99]

J-Suffix (H-08)

Dimensions shown in inches and (millimeters)

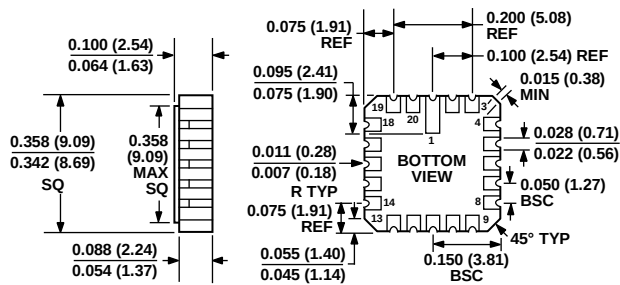
022306-A



COMPLIANT TO JEDEC STANDARDS MS-001
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Figure 46. 8-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body, P-Suffix (N-8)
Dimensions shown in inches and (millimeters)

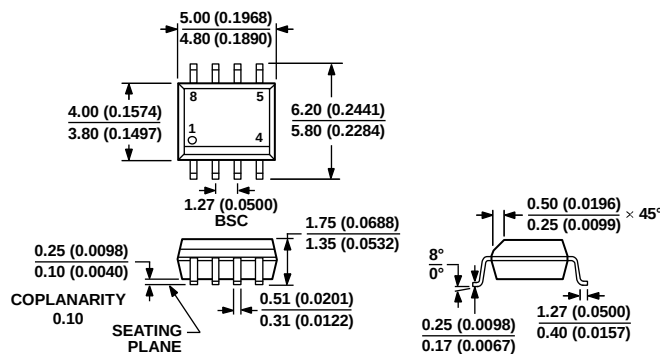
070606-A



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Figure 47. 20-Terminal Ceramic Leadless Chip Carrier [LCC]
RC-Suffix (E-20-1)
Dimensions shown in inches and (millimeters)

002106-A



COMPLIANT TO JEDEC STANDARDS MS-012-A A
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Figure 48. 8-Lead Standard Small Outline Package [SOIC_N]
Narrow Body, S-Suffix (R-8)
Dimensions shown in millimeters and (inches)

012407-A

REF01/REF02/REF03

REF01 ORDERING GUIDE

Model ^{1, 2}	Initial Accuracy (mV)	Temperature Range	Package Description	Package Option
REF01AJ/883C	±30	–55°C to +125°C	8-Pin TO-99	J-Suffix (H-08)
REF01CJ	±100	0°C to 70°C	8-Pin TO-99	J-Suffix (H-08)
REF01EZ	±30	–40°C to +85°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF01HZ	±50	–40°C to +85°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF01CPZ	±100	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
REF01HPZ	±50	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
REF01CS	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF01CS-REEL	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF01CS-REEL7	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF01CSZ	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF01CSZ-REEL	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF01CSZ-REEL7	±100	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)

¹ Contact sales for 883 data sheet.

² Z = RoHS Compliant Part.

REF02 ORDERING GUIDE

Model ^{1, 2}	Initial Accuracy (mV)	Temperature Range	Package Description	Package Option
REF02AJ/883C	±15	–55°C to +125°C	8-Pin TO-99	J-Suffix (H-08)
REF02AZ	±15	–55°C to +125°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF02AZ/883C	±15	–55°C to +125°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF02CP	±50	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
REF02CPZ	±50	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
REF02CS	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02CS-REEL	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02CS-REEL7	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02CSZ	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02CSZ-REEL	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02CSZ-REEL7	±50	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02EZ	±15	–40°C to +85°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF02HZ	±25	–40°C to +85°C	8-Lead Cerdip	Z-Suffix (Q-8)
REF02HPZ	±25	–40°C to +85°C	8-Lead PDIP	P-Suffix (N-8)
REF02HSZ	±25	–40°C to +85°C	8-Lead SOIC_N	S-Suffix (R-8)
REF02RC/883	±25	–55°C to +125°C	20-Terminal LCC	RC-Suffix (E-20-1)
REF02Z	±25	–55°C to +125°C	8-Lead Cerdip	Z-Suffix (Q-8)

¹ Contact sales for 883 data sheet.

² Z = RoHS Compliant Part.

REF03 ORDERING GUIDE

Model ¹	Initial Accuracy (mV)	Temperature Range	Package Description	Package Option
REF03GPZ	±15	–40°C to +85°C	8-Lead PDIP	N-8 (P-Suffix)
REF03GSZ	±15	–40°C to +85°C	8-Lead SOIC_N	R-8 (P-Suffix)
REF03GSZ-REEL	±15	–40°C to +85°C	8-Lead SOIC_N	R-8 (P-Suffix)
REF03GSZ-REEL7	±15	–40°C to +85°C	8-Lead SOIC_N	R-8 (P-Suffix)

¹ Z = RoHS Compliant Part.

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